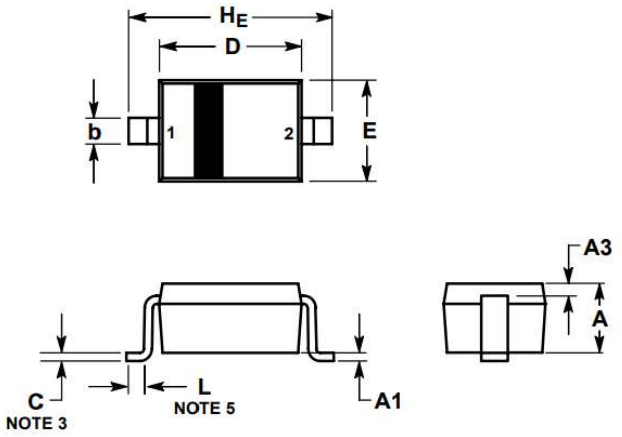
Zener Voltage Regulators
200mW Surface Mount Zener Diodes

This series of Zener diodes is packaged in a SOD–323 surface mount package that has a power dissipation of 200 mW. They are designed to provide voltage regulation protection and are especially attractive in situations where space is at a premium. They are well suited for applications such as cellular phones, hand held portables, and high density PC boards.

SOD-323

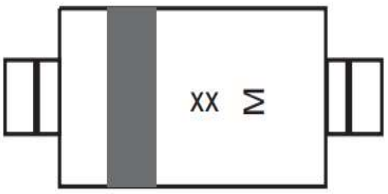


DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.90	1.00	0.031	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A3	0.15 REF			0.006 REF		
b	0.25	0.32	0.4	0.010	0.012	0.016
C	0.089	0.12	0.177	0.003	0.005	0.007
D	1.60	1.70	1.80	0.062	0.066	0.070
E	1.15	1.25	1.35	0.045	0.049	0.053
L	0.08			0.003		
H_E	2.30	2.50	2.70	0.090	0.098	0.105

Features
- Standard Zener Breakdown Voltage Range – 2.0 V to 75 V
- Steady State Power Rating of 200 mW
- Small Body Outline Dimensions: 0.067" x 0.049"(1.7 mm x 1.25 mm)
- Low Body Height: 0.035" (0.9 mm)
- Package Weight: 4.507mg/unit
- ESD Rating of Class 3 per Human Body Model
- Pb-Free package is available.
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.
- We declare that the material of product compliance with RoHS requirements

Mechanical Data
- Case : Void-free, transfer-molded plastic
- Finish : All external surface corrosion resistant
- Maximun Case Temperature for Soldering Purposes : 260°C for 10 Seconds
- Polarity : Cathode indicated by polarity band
- Flammablity Rating : UL 94 V−0
- Mounting Position : Any

Marking



XX = Specific Device Code
M = Date Code

Cathode Anode

Maximum Ratings

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Parameter		Symbol	Rated Value	Unit	Remark
Total Power Dissipation on FR-5 Board,(Note 1)at Ta=25℃ Derate above 25℃		P_D	200 1.5	mW mW/℃	Note 1
Thermal Resistance from Junction to Ambient		Rth(j-a)	635	℃/W	
Junction and Storage Temperature Range		T_J, T_{STG}	-65 to +150	℃	

Note 1. FR-4 Minimum Pad

Electrical Characteristics (T_A = 25°C unless otherwise noted, V_F = 0.9 V Max. @ I_F = 10 mA for all types)

Device	Device Marking	Zener Voltage				Zener Impedance (Note 5)			Leakage Current I_R @ V_R		ΘV_Z(mV/k)@I_{ZT}		Capacitance @VR=0, f=1MHz
		V_Z (V)			I_{ZT}	Z_{ZT} @	Z_{ZK} @ I_{ZK}	I_{ZK}	I_R	V_R	mV/k		C
		Min	Nom	Max	mA	Ω	Ω	mA	uA	Volts	Min	Max	pF
LM3Z2V0T1G	WY	1.91	2.0	2.09	5.0	100	600	1.0	150	1.0	–3.5	0	450
LM3Z2V4T1G	00	2.2	2.4	2.6	5.0	100	1000	0.5	50	1.0	–3.5	0	450
LM3Z2V7T1G	01	2.5	2.7	2.9	5.0	100	1000	0.5	20	1.0	–3.5	0	450
LM3Z3V0T1G	02	2.8	3.0	3.2	5.0	100	1000	0.5	10	1.0	–3.5	0	450
LM3Z3V3T1G	05	3.1	3.3	3.5	5.0	95	1000	0.5	5.0	1.0	–3.5	0	450
LM3Z3V6T1G	06	3.4	3.6	3.8	5.0	90	1000	0.5	5.0	1.0	–3.5	0	450
LM3Z3V9T1G	07	3.7	3.9	4.1	5.0	90	1000	0.5	3.0	1.0	–3.5	–2.5	450
LM3Z4V3T1G	08	4.0	4.3	4.6	5.0	90	1000	0.5	3.0	1.0	–3.5	0	450
LM3Z4V7T1G	09	4.4	4.7	5.0	5.0	80	800	0.5	3.0	2.0	–3.5	0.2	260
LM3Z5V1T1G	0A	4.8	5.1	5.4	5.0	60	800	0.5	2.0	2.0	–2.7	1.2	225
LM3Z5V6T1G	0C	5.2	5.6	6.0	5.0	40	700	0.5	1.0	2.0	–2.0	2.5	200
LM3Z6V2T1G	0E	5.8	6.2	6.6	5.0	10	100	0.5	3.0	4.0	0.4	3.7	185
LM3Z6V8T1G	0F	6.4	6.8	7.2	5.0	15	160	0.5	2.0	4.0	1.2	4.5	155
LM3Z7V5T1G	0G	7.0	7.5	7.9	5.0	15	160	0.5	1.0	5.0	2.5	5.3	140
LM3Z8V2T1G	0H	7.7	8.2	8.7	5.0	15	160	0.5	0.7	5.0	3.2	6.2	135
LM3Z9V1T1G	0K	8.5	9.1	9.6	5.0	15	160	0.5	0.2	7.0	3.8	7.0	130
LM3Z10VT1G	0L	9.4	10.0	10.6	5.0	20	160	0.5	0.1	8.0	4.5	8.0	130
LM3Z11VT1G	0M	10.4	11.0	11.6	5.0	20	160	0.5	0.1	8.0	5.4	9.0	130
LM3Z12VT1G	0N	11.4	12.0	12.7	5.0	25	80	0.5	0.1	8.0	6.0	10.0	130
LM3Z13VT1G	0P	12.4	13.25	14.1	5.0	30	80	0.5	0.1	8.0	7.0	11.0	120
LM3Z15VT1G	0T	14.3	15.0	15.8	5.0	30	400	0.5	0.05	10.5	9.2	13.0	110
LM3Z16VT1G	0U	15.3	16.2	17.1	5.0	40	400	0.5	0.05	11.2	10.4	14.0	105
LM3Z18VT1G	0W	16.8	18.0	19.1	5.0	45	400	0.5	0.05	12.6	12.4	16.0	100
LM3Z20VT1G	0Z	18.8	20.0	21.2	5.0	55	500	0.5	0.05	14.0	14.4	18.0	85
LM3Z22VT1G	10	20.8	22.0	23.3	5.0	55	500	0.5	0.05	15.4	16.4	20.0	85
LM3Z24VT1G	11	22.8	24.2	25.6	5.0	70	120	0.5	0.05	16.8	18.4	22.0	80
LM3Z27VT1G	12	25.1	27.0	28.9	2.0	80	300	0.5	0.05	18.9	21.4	25.3	70
LM3Z30VT1G	14	28.0	30.0	32.0	2.0	80	300	0.5	0.05	21.0	24.4	29.4	70
LM3Z33VT1G	18	31.0	33.0	35.0	2.0	80	300	0.5	0.05	23.2	27.4	33.4	70
LM3Z36VT1G	19	34.0	36.0	38.0	2.0	90	500	0.5	0.05	25.2	30.4	37.4	70
LM3Z39VT1G	20	37.0	39.0	41.0	2.0	130	500	0.5	0.05	27.3	33.4	41.2	45
LM3Z43VT1G	21	40.0	43.0	46.0	2.0	150	500	0.5	0.05	30.1	37.6	46.6	40
LM3Z47VT1G	1A	44.0	47.0	50.0	2.0	170	500	0.5	0.05	32.9	42.0	51.8	40
LM3Z51VT1G	1C	48.0	51.0	54.0	2.0	180	500	0.5	0.05	35.7	46.6	57.2	40
LM3Z56VT1G	1D	52.0	56.0	60.0	2.0	200	500	0.5	0.05	39.2	52.2	63.8	40
LM3Z62VT1G	1E	58.0	62.0	66.0	2.0	215	500	0.5	0.05	43.4	58.8	71.6	35
LM3Z68VT1G	1F	64.0	68.0	72.0	2.0	240	500	0.5	0.05	47.6	65.6	79.8	35
LM3Z75VT1G	1G	70.0	75.0	79.0	2.0	255	500	0.5	0.05	52.5	73.4	88.6	35

2. Zener voltage is measured with a pulse test current IZ at an ambient temperature of 25°C.

Ratings and Characteristics Curves (Ta=25℃ unless otherwise noted)

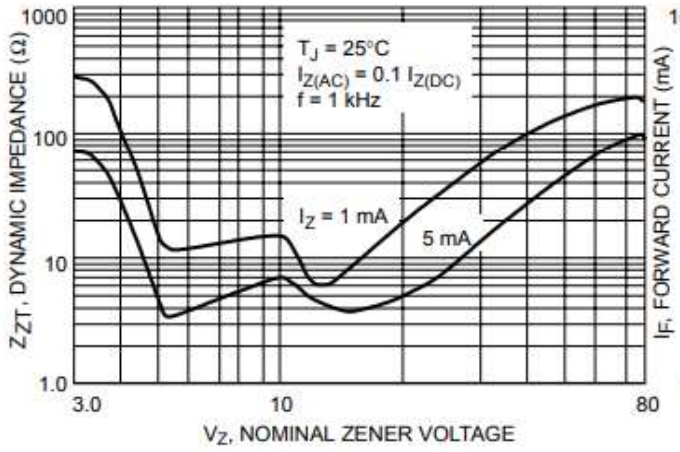


Figure 1. Effect of Zener Voltage on Zener Impedance

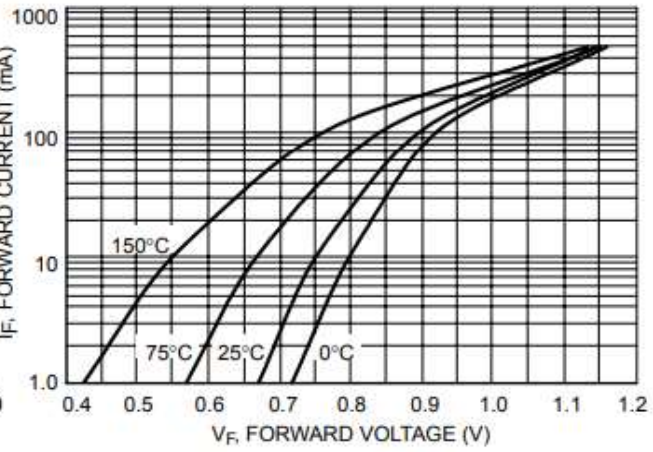


Figure 2. Typical Forward Voltage

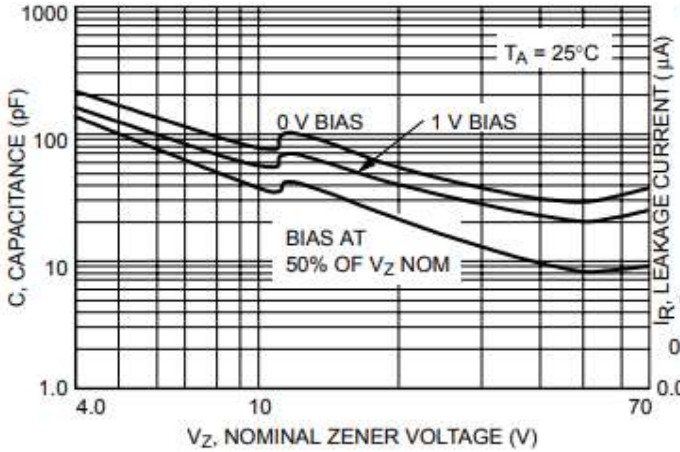


Figure 3. Typical Capacitance

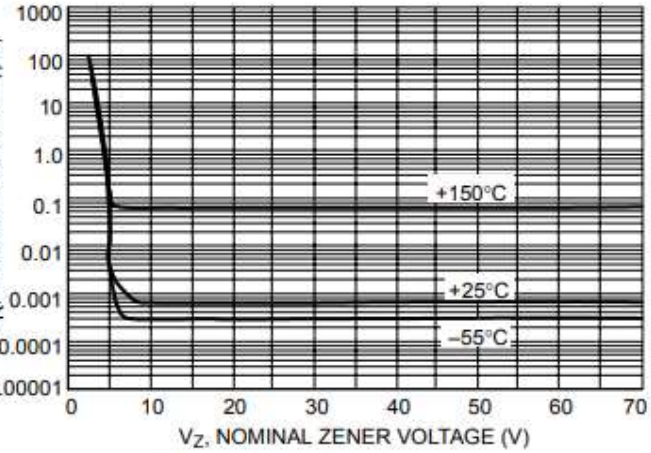


Figure 4. Typical Leakage Current

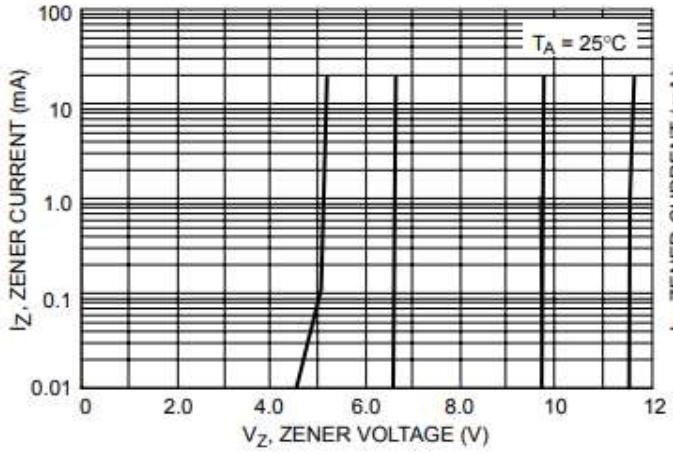


Figure 5. Zener Voltage versus Zener Current (V_Z Up to 12 V)

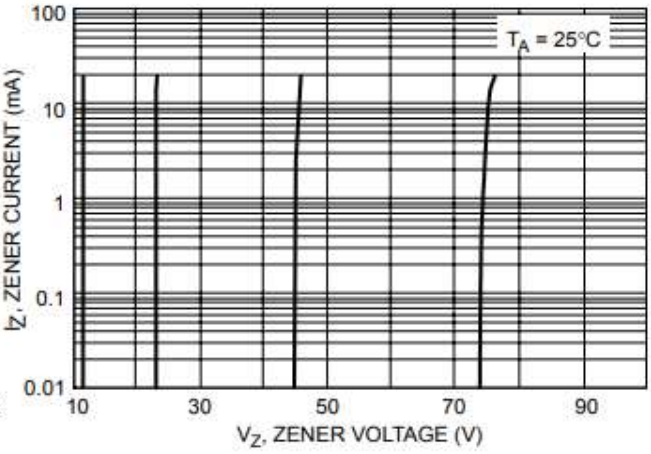


Figure 6. Zener Voltage versus Zener Current (12 V to 75 V)

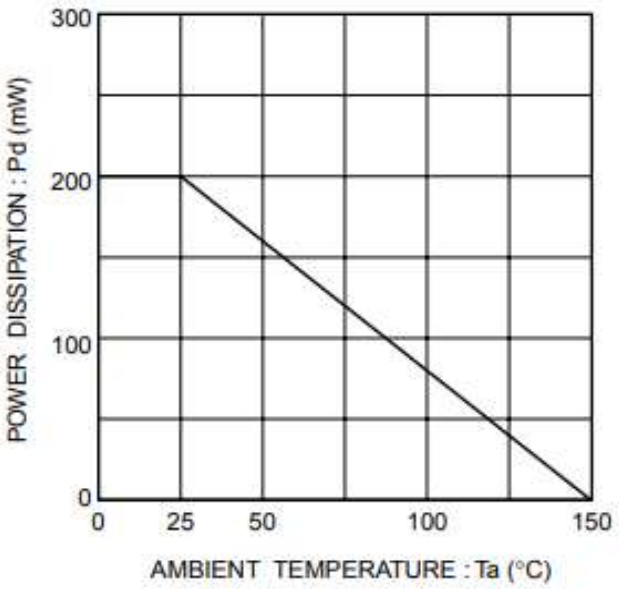
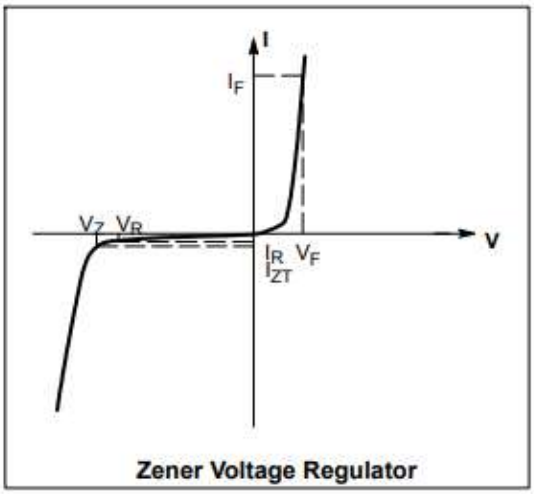


Figure 7. Steady State Power Derating

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted,
V_F = 0.9 V Max. @ I_F = 10 mA for all types)

Symbol	Parameter
V_Z	Reverse Zener Voltage @ I_{ZT}
I_{ZT}	Reverse Current
Z_{ZT}	Maximum Zener Impedance @ I_{ZT}
I_{ZK}	Reverse Current
Z_{ZK}	Maximum Zener Impedance @ I_{ZK}
I_R	Reverse Leakage Current @ V_R
V_R	Reverse Voltage
I_F	Forward Current
V_F	Forward Voltage @ I_F
ΘV_Z	Maximum Temperature Coefficient of V_Z
C	Max. Capacitance @V_R = 0 and f = 1 MHz



Zener Voltage Regulator